## NSN 5961-01-615-7670

**Fiig:** A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-615-7670 **Inclosure Material:** Plastic **Overall Length:** Between 0.110 inches and 0.118 inches **Terminal Length:** Between 0.004 inches and 0.024 inches **Overall Height:** Between 0.035 inches and 0.057 inches **Overall Width:** Between 0.102 inches and 0.118 inches **Function For Which Designed:** Voltage regulator **Component Name And Quantity:** 1 semiconductor device diode Voltage Rating In Volts Per Characteristic: 9.0 reverse voltage, peak 1st semiconductor device diode **Current Rating Per Characteristic:** 200.0 milliamperes forward current, average 1st semiconductor device diode **Capacitance Rating In Picofarads:** 7.0 and 10.0 1st semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Product Name:** Low capacity diode array **Special Features:** Complies with iec61000-4-2 level 4 and military standard 883c- method 3015-6, verylow capacitance per diode: c<5pf, very low leakage current: ir<1 ua, **Terminal Type And Quantity:** 6 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No